FUNCTIONAL TRUTH TABLE (X = Don't Care)

Clock	Write Enable	Data	16−Bit Tap	32−Bit Tap	48−Bit Tap	64−Bit Tap
0	0	X	Content of 16−Bit Displayed	Content of 32−Bit Displayed	Content of 48−Bit Displayed	Content of 64−Bit Displayed
0	1	X	High Impedance	High Impedance	High Impedance	High Impedance
1	0	X	Content of 16−Bit Displayed	Content of 32−Bit Displayed	Content of 48−Bit Displayed	Content of 64−Bit Displayed
1	1	X	High Impedance	High Impedance	High Impedance	High Impedance
⎍	0	Data entered into 1st Bit	Content of 16−Bit Displayed	Content of 32−Bit Displayed	Content of 48−Bit Displayed	Content of 64−Bit Displayed
⎍	1	Data entered into 1st Bit	Data at tap entered into 17−Bit	Data at tap entered into 33−Bit	Data at tap entered into 49−Bit	High Impedance
⎎	0	X	Content of 16−Bit Displayed	Content of 32−Bit Displayed	Content of 48−Bit Displayed	Content of 64−Bit Displayed
⎎	1	X	High Impedance	High Impedance	High Impedance	High Impedance

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	− 55°C Min	− 55°C Max	25°C Min	25°C Typ (Note 2)	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level V_{in} = V_{DD} or 0	V_{OL}	5.0	−	0.05	−	0	0.05	−	0.05	Vdc
		10	−	0.05	−	0	0.05	−	0.05	
		15	−	0.05	−	0	0.05	−	0.05	
"1" Level V_{in} = 0 or V_{DD}	V_{OH}	5.0	4.95	−	4.95	5.0	−	4.95	−	Vdc
		10	9.95	−	9.95	10	−	9.95	−	
		15	14.95	−	14.95	15	−	14.95	−	
Input Voltage "0" Level	V_{IL}									Vdc
(V_O = 4.5 or 0.5 Vdc)		5.0	−	1.5	−	2.25	1.5	−	1.5	
(V_O = 9.0 or 1.0 Vdc)		10	−	3.0	−	4.50	3.0	−	3.0	
(V_O = 13.5 or 1.5 Vdc)		15	−	4.0	−	6.75	4.0	−	4.0	
"1" Level	V_{IH}									Vdc
(V_O = 0.5 or 4.5 Vdc)		5.0	3.5	−	3.5	2.75	−	3.5	−	
(V_O = 1.0 or 9.0 Vdc)		10	7.0	−	7.0	5.50	−	7.0	−	
(V_O = 1.5 or 13.5 Vdc)		15	11	−	11	8.25	−	11	−	
Output Drive Current	I_{OH}									mAdc
(V_{OH} = 2.5 Vdc) Source		5.0	–3.0	−	–2.4	–4.2	−	–1.7	−	
(V_{OH} = 4.6 Vdc)		5.0	–0.64	−	–0.51	–0.88	−	–0.36	−	
(V_{OH} = 9.5 Vdc)		10	–1.6	−	–1.3	–2.25	−	–0.9	−	
(V_{OH} = 13.5 Vdc)		15	–4.2	−	–3.4	–8.8	−	–2.4	−	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.64	−	0.51	0.88	−	0.36	−	mAdc
(V_{OL} = 0.5 Vdc)		10	1.6	−	1.3	2.25	−	0.9	−	
(V_{OL} = 1.5 Vdc)		15	4.2	−	3.4	8.8	−	2.4	−	
Input Current	I_{in}	15	−	±0.1	−	±0.00001	±0.1	−	±1.0	μAdc
Input Capacitance (V_{in} = 0)	C_{in}	−	−	−	−	5.0	7.5	−	−	pF
Quiescent Current (Per Package)	I_{DD}	5.0	−	5.0	−	0.005	5.0	−	150	μAdc
		10	−	10	−	0.010	10	−	300	
		15	−	20	−	0.015	20	−	600	
Total Supply Current (Note 3, 4) (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0	I_T = (4.2 μA/kHz) f + I_{DD}							μAdc
		10	I_T = (8.8 μA/kHz) f + I_{DD}							
		15	I_T = (13.7 μA/kHz) f + I_{DD}							
Three−State Leakage Current	I_{TL}	15	−	±0.1	−	±0.0001	±0.1	−	±3.0	μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF: $I_T(C_L) = I_T(50\ pF) + (C_L - 50)$ Vfk where: I_T is in μA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD}	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns t_{TLH}, t_{THL} = (0.65 ns/pF) C_L + 9.5 ns	t_{TLH}, t_{THL}	 5.0 10 15	 – – –	 100 50 40	 200 100 80	ns
Propagation Delay Time t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 390 ns t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 177 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 115 ns	t_{PLH}, t_{PHL}	 5.0 10 15	 – – –	 475 210 140	 770 300 215	ns
Clock Pulse Width	t_{WH}	5.0 10 15	330 125 100	170 75 60	– – –	ns
Clock Pulse Frequency	f_{cl}	5.0 10 15	– – –	3.0 6.7 8.3	1.5 4.0 5.3	MHz
Clock Pulse Rise and Fall Time	t_{TLH}, t_{THL}	5.0 10 15	See (Note 7)			–
Data to Clock Setup Time	t_{su}	5.0 10 15	0 10 15	– 40 – 15 0	– – –	ns
Data to Clock Hold Time	t_h	5.0 10 15	150 75 35	75 25 10	– – –	ns
Write Enable to Clock Setup Time	t_{su}	5.0 10 15	400 200 110	170 65 50	– – –	ns
Write Enable to Clock Release Time	t_{rel}	5.0 10 15	380 180 100	160 55 40	– – –	ns

5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.
7. When shift register sections are cascaded, the maximum rise and fall time of the clock input should be equal to or less than the rise and fall time of the data outputs, driving data inputs, plus the propagation delay of the output driving stage.

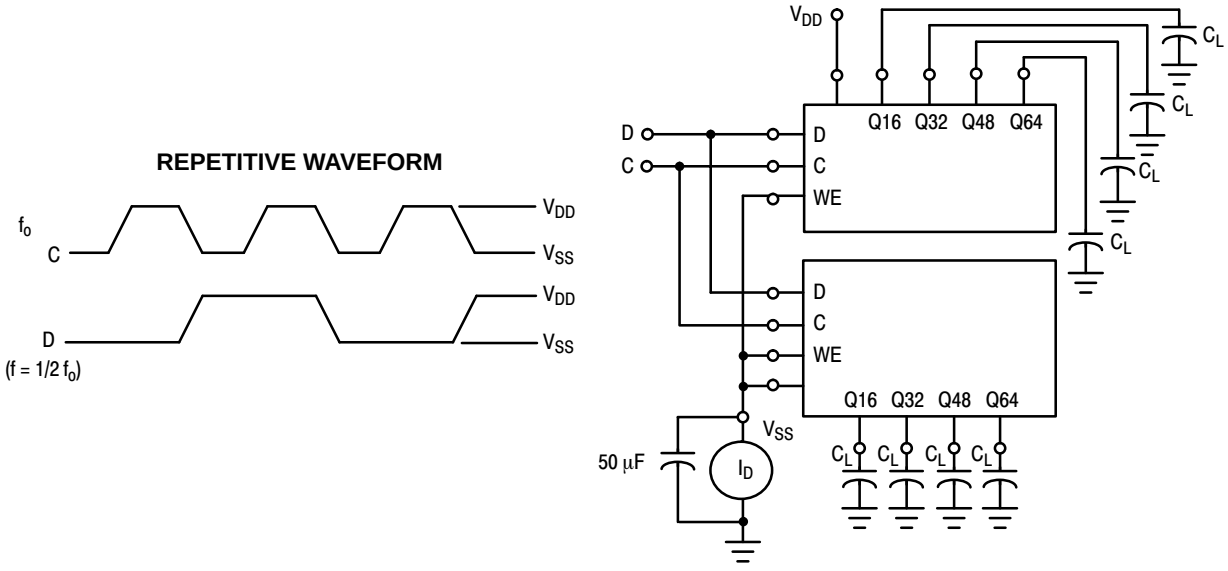
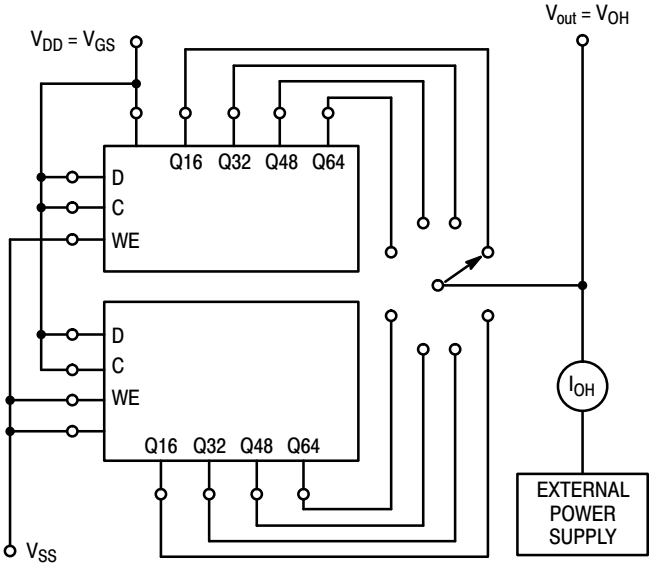
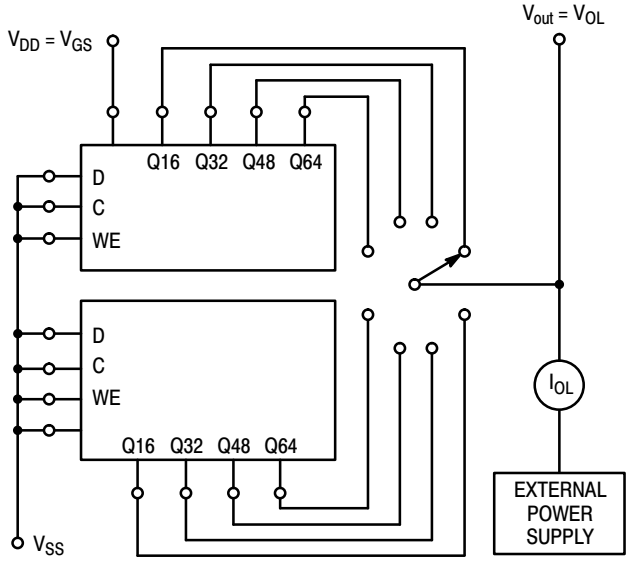


Figure 1. Power Dissipation Test Circuit and Waveform



(Output being tested should be in the high−logic state)

Figure 2. Typical Output Source Current Characteristics Test Circuit



(Output being tested should be in the low−logic state)

Figure 3. Typical Output Sink Current Characteristics Test Circuit

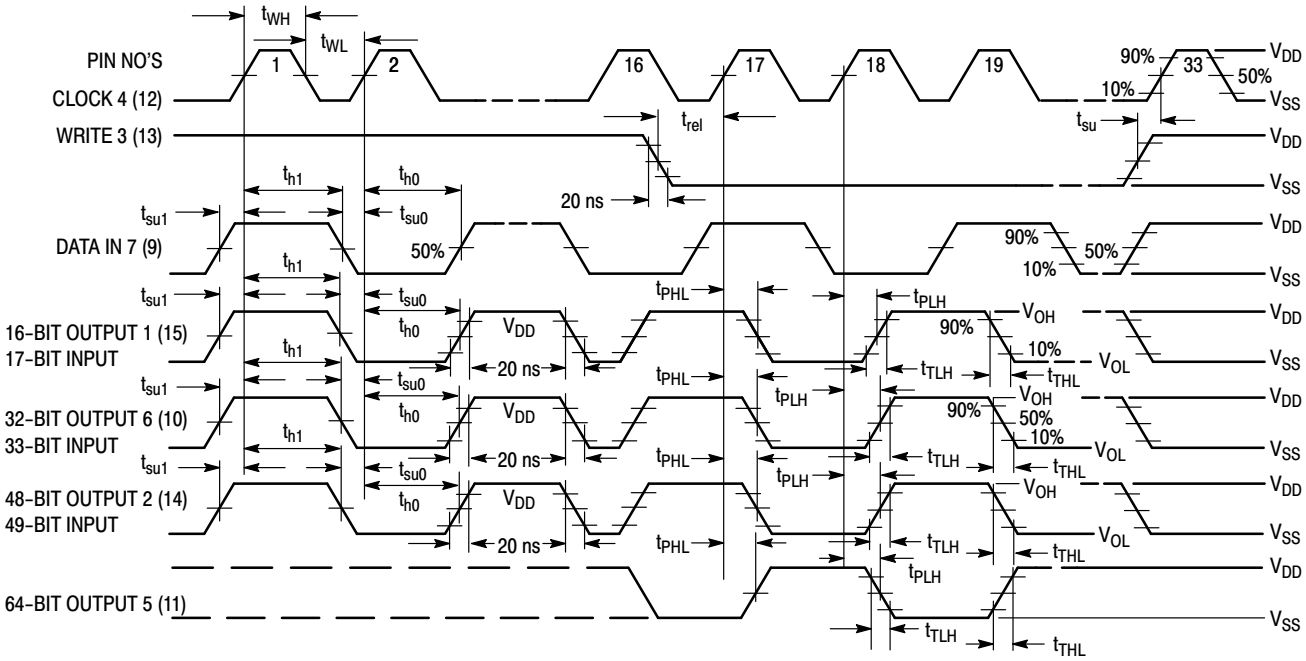
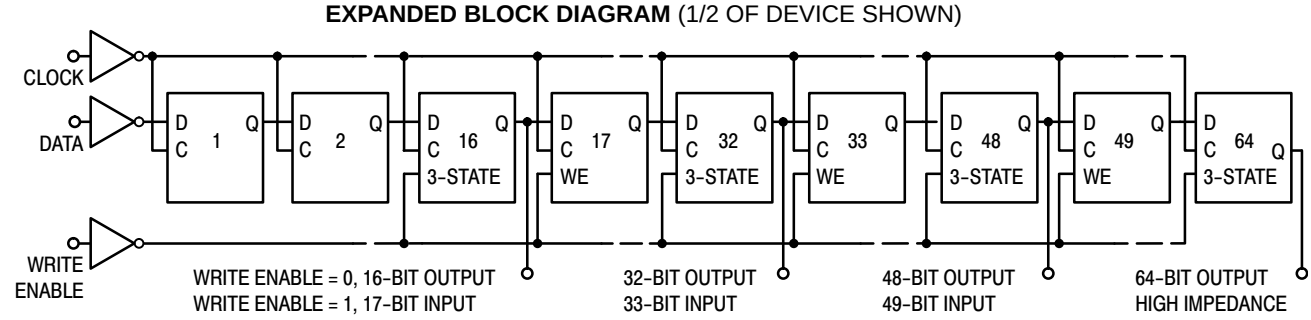


Figure 4. AC Test Waveforms

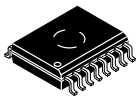
EXPANDED BLOCK DIAGRAM (1/2 OF DEVICE SHOWN)



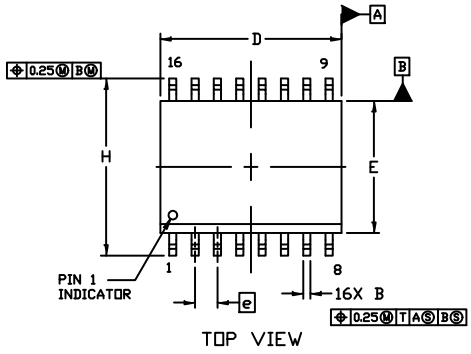
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

SOIC−16 WB
CASE 751G
ISSUE E

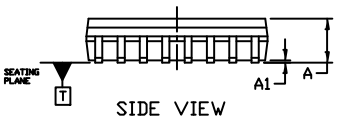
DATE 08 OCT 2021



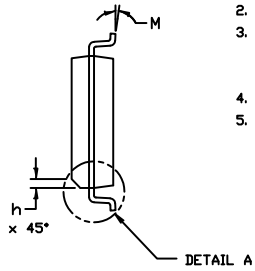
1
SCALE 1:1



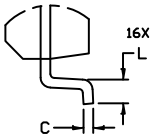
TOP VIEW



SIDE VIEW



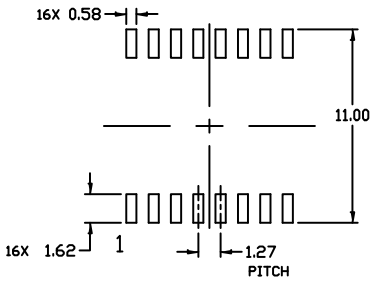
END VIEW



DETAIL A
2X SCALE

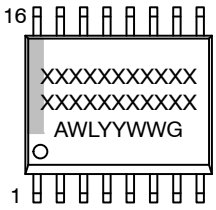
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION OR FLASH TO BE 0.15 PER SIDE.

	MILLIMETERS	
DIM	MIN.	MAX.
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	10.15	10.45
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.53 REF	
L	0.50	0.90
M	0°	7°



RECOMMENDED
MOUNTING FOOTPRINT

GENERIC
MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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